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October 2013

FGA60N65SMD 650 V, 60 A Field Stop IGBT

Features

- Maximum Junction Temperature : T_J = 175^oC
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.9 V(Typ.) @ I_{C} = 60 A$
- Fast Switching : E_{OFF} = 7.5 uJ/A
- Tighten Parameter Distribution
- RoHS Compliant

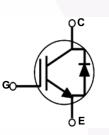
Applications

• Solar Inverter, UPS, Welder, PFC, Telecom, ESS

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2nd generation IGBTs offer the optimum performance for solar inverter, UPS, welder, telecom, ESS and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
*GES	Transient Gate to Emitter Voltage		± 30	V
I _C	Collector Current	@ T _C = 25 ^o C	120	A
'C	Collector Current	@ T _C = 100°C	60	A
I _{CM (1)}	Pulsed Collector Current		180	A
I _F	Diode Forward Current	@ T _C = 25 ^o C	60	A
	Diode Forward Current	@ T _C = 100°C	30	A
I _{FM (1)}	Pulsed Diode Maximum Forward Current		180	А
P _D	Maximum Power Dissipation	@ T _C = 25 ^o C	600	W
	Maximum Power Dissipation @ $T_{C} = 100^{\circ}C$		300	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.25	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	1.1	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	-	40	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGA60N65SMD	FGA60N65SMD	TO-3PN	-	-	30

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	toriotion					
		V 0V 1 2500 A	650	-		V
BV _{CES}	Collector to Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250\mu A$	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 250 \mu A$	-	0.6	-	V/ºC
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	250	μA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250μA, V _{CE} = V _{GE}	3.5	4.5	6.0	V
		$I_{\rm C} = 60$ A, $V_{\rm GE} = 15$ V	-	1.9	2.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_{C} = 60A, V_{GE} = 15V,$ $T_{C} = 175^{\circ}C$	-	2.1	-	V
Dynamic C	Characteristics		·			
C _{ies}	Input Capacitance		-	2915	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30V$, $V_{GE} = 0V$,	-	270	-	pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz	-	85	-	pF
	Characteristics	1				
t _{d(on)}	Turn-On Delay Time		T -	18	27	ns
t _r	Rise Time	-	-	47	70	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400V, I _C = 60A,	-	104	146	ns
t _f	Fall Time	$R_{G} = 3\Omega, V_{GE} = 15V,$	-	50	68	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$	-	1.54	2.31	mJ
E _{off}	Turn-Off Switching Loss		-	0.45	0.60	mJ
E _{ts}	Total Switching Loss		-	1.99	2.91	mJ
t _{d(on)}	Turn-On Delay Time		-	18	-	ns
t _r	Rise Time	1	-	41	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400V, I _C = 60A,	-	115	-	ns
t _f	Fall Time	$R_G = 3\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 175^{\circ}C$	-	48	-	ns
E _{on}	Turn-On Switching Loss		-	2.08	-	mJ
_	Turn-Off Switching Loss	1	-	0.78	-	mJ
E _{off}	Turn-On Switching L035			00		

Electrical Characteristics of the IGBT (Continued)

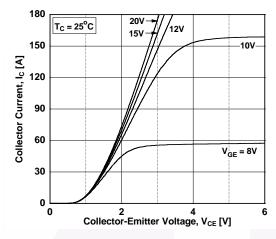
Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	189	284	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400V, I _C = 60A, V _{GE} = 15V	-	20	30	nC
Q _{gc}	Gate to Collector Charge		-	91	137	nC

Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

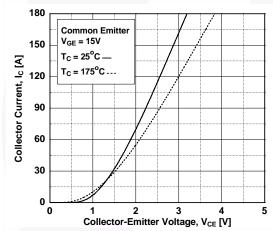
Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V _{FM}	Diode Forward Voltage	I _F = 30A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	2.1	2.6	V
VFM Diode i of ward voltage			T _C = 175°C	-	1.7	-	
E _{rec}	Reverse Recovery Energy		T _C = 175 ^o C	-	127	-	uJ
t _{rr}		I _F =30A, dI _F /dt = 200A/μs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	47	-	ns
rr			T _C = 175 ^o C	-	212	-	110
0	Q _{rr} Diode Reverse Recovery Charge		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	87	-	nC
αn			T _C = 175 ^o C	-	933	-	110

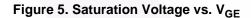
Typical Performance Characteristics











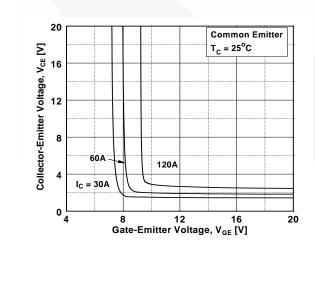
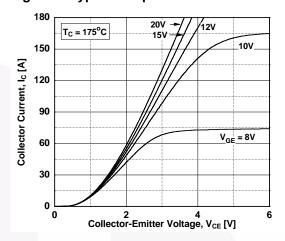
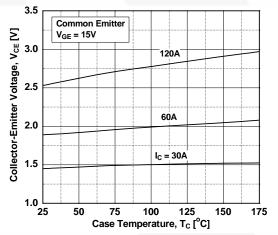
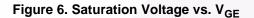


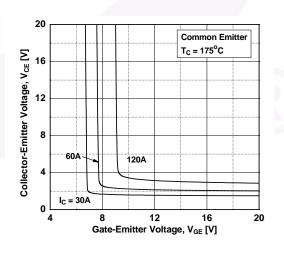
Figure 2. Typical Output Characteristics



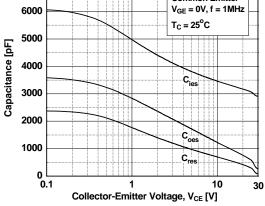








Typical Performance Characteristics Figure 7. Capacitance Characteristics 7000 Common Emitter Yung OV for 1000





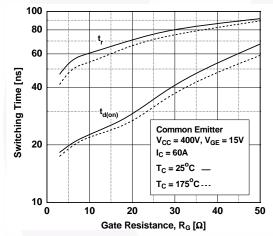


Figure 11. Switching Loss vs. Gate Resistance

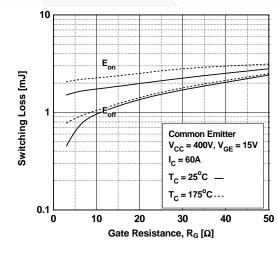
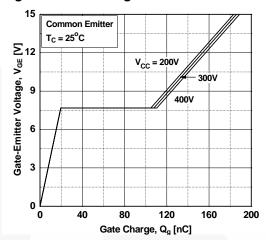
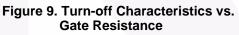
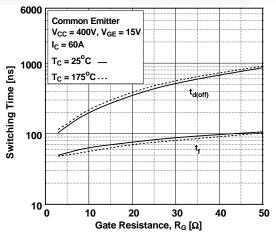
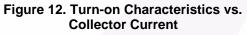


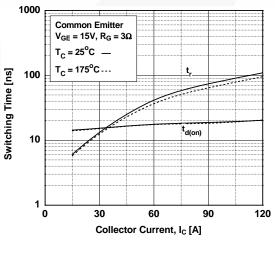
Figure 8. Gate charge Characteristics







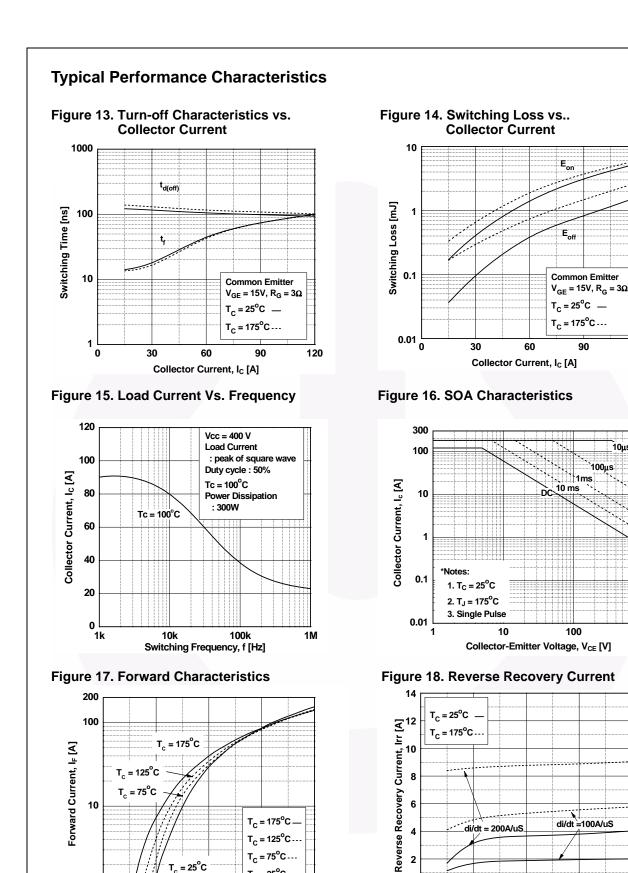




120

10µs

1000



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Forward Current, I_F [A]

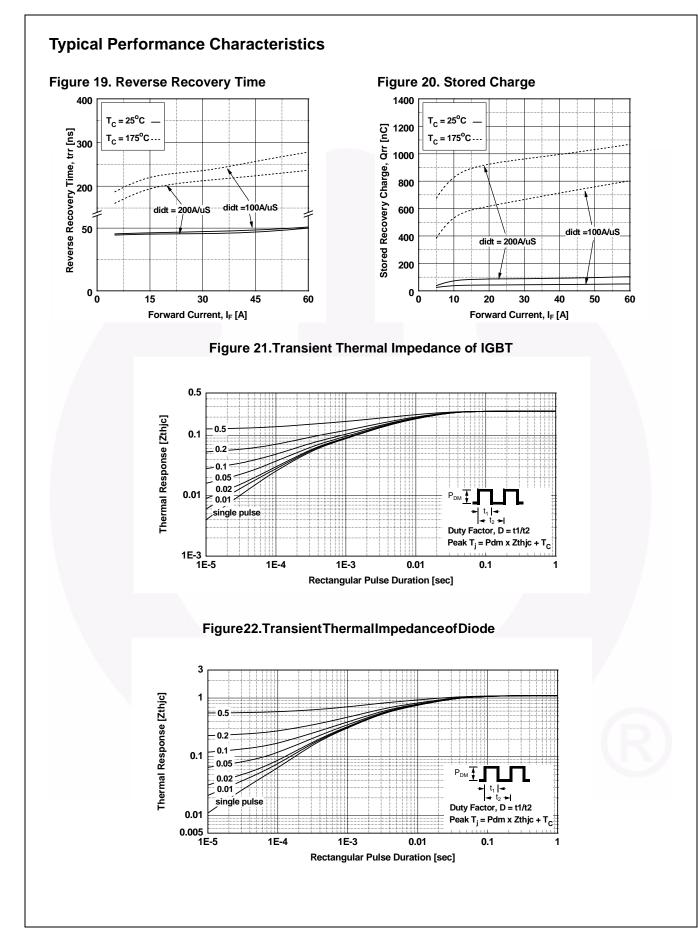
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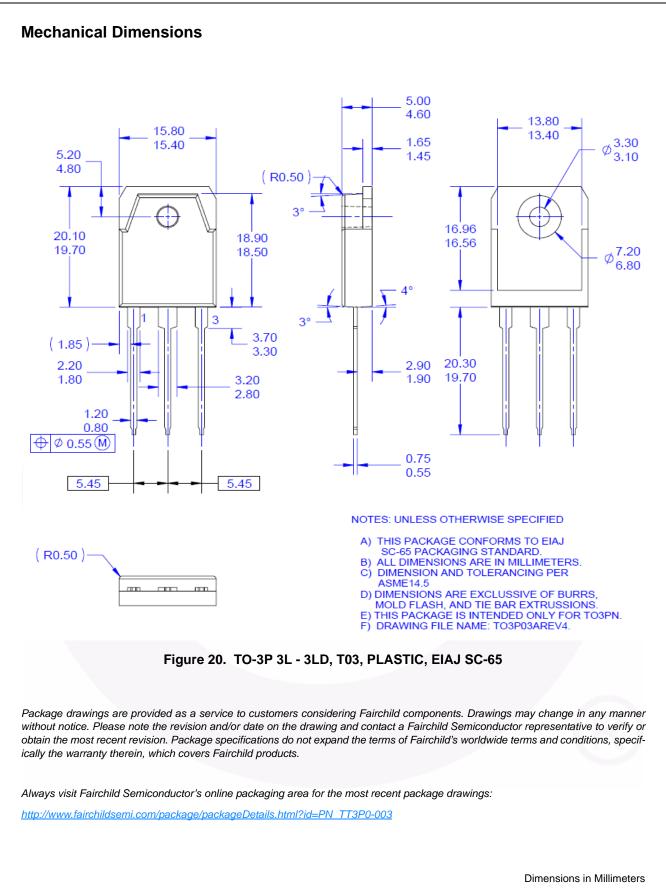
T_C = 25°C

3

2

Forward Voltage, V_F [V]





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650 V, 60 A Field Stop IGBT

GA60N65SMD ---

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